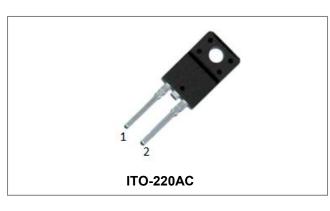


MBRF560L



MBRF560L SCHOTTKY RECTIFIER



150 °C T_J operation

Features

- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Circuit Diagram



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm V _{rwm} Vr	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=125°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	125	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 ℃	0.53	0.60	V
Reverse Current at DC condition*	I _{R1}	@V _R = rated V _R , T _J = 25 $^{\circ}$ C	0.09	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 ℃	18	30	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 ℃ f _{SIG} = 1MHz	180	220	pF
Typical Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μs, duty cycle < 2%

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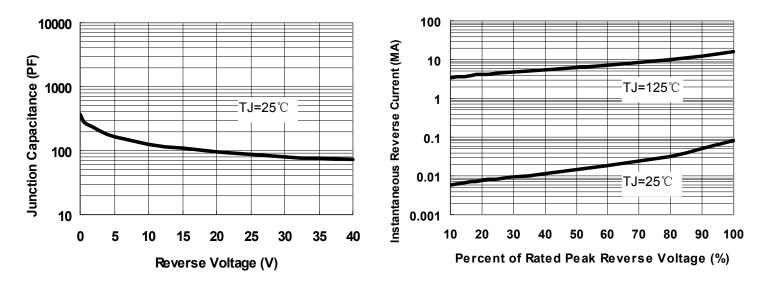




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	3	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

Ratings and Characteristics Curves







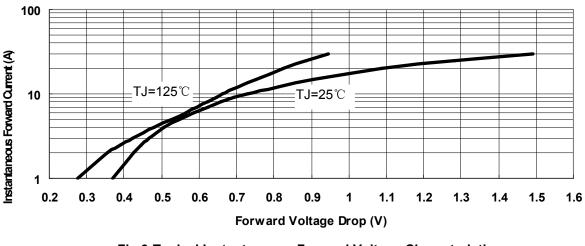


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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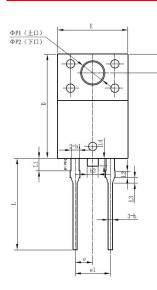


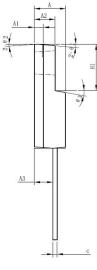
MBRF560L



Mechanical Dimensions ITO-220AC

8

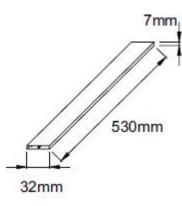




SYMBOL	Millimeters			
STWBOL	MIN.	TYP.	MAX.	
A	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
С	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	-	2.55	-	
e1	-	5.10	-	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
L4	-	1.10	1.50	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦΡ2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

2-1,94 an an an 0

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR

F

5

L

60

SSG

ΥY

ww L

- = Device Type
 - = Package type = Forward Current (5A)
 - = Reverse Voltage (60V) = Low VF = SSG
- - = Year
 - = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
MBRF560L	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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Technical Data Data Sheet N0818, Rev.B





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